



DOCKET NO. SC12885TP

UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT Marius Orlowski et al. GROUP ART UNIT: 2823
APPLN. NO.: 10/631,093 EXAMINER: Belur V. Keshavan
FILED: July 31, 2003 CONFIRMATION No.: 1735
TITLE: METHOD OF FORMING A TRANSISTOR HAVING
MULTIPLE CHANNELS AND STRUCTURE THEREOF

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on 5-4-05

Pat Thomas
Signature

PAT THOMAS
Printed Name of Person Signing Certificate

COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This paper is filed contemporaneous with the filing of the issue fee for this
application. Entrance of the comments provided below regarding the statement of
reasons for allowance provided by the Examiner is respectfully requested.

FEES

Applicants authorize the charging of Deposit Account No. 503079
(Freescale Semiconductor, Inc.) for any fees owed in connection with this
application, or credit Deposit Account No. 503079 (Freescale Semiconductor, Inc.)
for any refunds.

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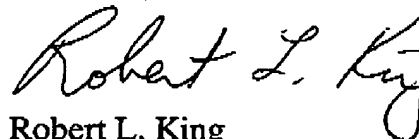
REMARKS

In a communication mailed March 10, 2005, claims 13-25 were allowed. The Examiner provided a statement of reasons for allowance. To avoid the reasons from being construed out of context by implying that the points of novelty were completely contained in the sentences provided by the Examiner, Applicants are filing these remarks. Applicants submit that this application is distinguishable over the prior art due to the collective recitations in allowed independent claim 13. It is also Applicants' position that the claim recitals in the allowed dependent claims are also distinguishable over the prior art.

SEND CORRESPONDENCE TO:

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Respectfully submitted,



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